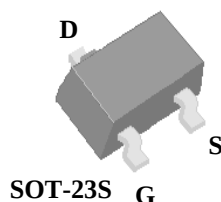


- ▼ Simple Drive Requirement
- ▼ Small Package Outline
- ▼ Surface Mount Device
- ▼ RoHS Compliant & Halogen-Free

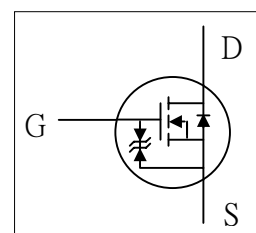


BV_{DSS}	60V
$R_{DS(ON)}$	2Ω
I_D	450mA

Description

XP2N7002 series are innovated design and silicon process technology to achieve the lowest possible on-resistance and fast switching performance. It provides the designer with an extreme efficient device for use in a wide range of power applications.

The SOT-23S package is universally used for all commercial-industrial applications.



Absolute Maximum Ratings@ $T_J=25^\circ\text{C}$ (unless otherwise specified)

Symbol	Parameter	Rating	Units
V_{DS}	Drain-Source Voltage	60	V
V_{GS}	Gate-Source Voltage	± 20	V
$I_D@T_A=25^\circ\text{C}$	Drain Current ³ , V_{GS} @ 10V	450	mA
$I_D@T_A=70^\circ\text{C}$	Drain Current ³ , V_{GS} @ 10V	360	mA
I_{DM}	Pulsed Drain Current ¹	950	mA
$P_D@T_A=25^\circ\text{C}$	Total Power Dissipation	0.7	W
T_{STG}	Storage Temperature Range	-55 to 150	$^\circ\text{C}$
T_J	Operating Junction Temperature Range	-55 to 150	$^\circ\text{C}$

Thermal Data

Symbol	Parameter	Value	Unit
R_{thj-a}	Maximum Thermal Resistance, Junction-ambient ³	180	$^\circ\text{C/W}$

Electrical Characteristics@T_j=25°C(unless otherwise specified)

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Units
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V, I _D =250uA	60	-	-	V
R _{DS(ON)}	Static Drain-Source On-Resistance ²	V _{GS} =10V, I _D =450mA	-	-	2	Ω
		V _{GS} =4.5V, I _D =200mA	-	-	4	Ω
V _{GS(th)}	Gate Threshold Voltage	V _{DS} =V _{GS} , I _D =250uA	1	-	2.5	V
g _{fs}	Forward Transconductance	V _{DS} =10V, I _D =450mA	-	400	-	mS
I _{DSS}	Drain-Source Leakage Current	V _{DS} =48V, V _{GS} =0V	-	-	25	uA
I _{GSS}	Gate-Source Leakage	V _{GS} =±20V, V _{DS} =0V	-	-	±30	uA
Q _g	Total Gate Charge	I _D =450mA	-	1	1.6	nC
Q _{gs}	Gate-Source Charge	V _{DS} =50V	-	0.5	-	nC
Q _{gd}	Gate-Drain ("Miller") Charge	V _{GS} =4.5V	-	0.5	-	nC
t _{d(on)}	Turn-on Delay Time	V _{DS} =30V	-	12	-	ns
t _r	Rise Time	I _D =450mA	-	10	-	ns
t _{d(off)}	Turn-off Delay Time	R _G =3.3Ω	-	56	-	ns
t _f	Fall Time	V _{GS} =10V	-	29	-	ns
C _{iss}	Input Capacitance	V _{GS} =0V	-	32	50	pF
C _{oss}	Output Capacitance	V _{DS} =25V	-	8	-	pF
C _{rss}	Reverse Transfer Capacitance	f=1.0MHz	-	6	-	pF

Source-Drain Diode

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Units
V _{SD}	Forward On Voltage ²	I _S =450mA, V _{GS} =0V	-	-	1.2	V

Notes:

- 1.Pulse width limited by Max. junction temperature.
- 2.Pulse test
- 3.Surface mounted on 1 in² copper pad of FR4 board t ≤ 10sec; 400°C/W when mounted on min. copper pad.

THIS PRODUCT IS SENSITIVE TO ELECTROSTATIC DISCHARGE, PLEASE HANDLE WITH CAUTION.

USE OF THIS PRODUCT AS A CRITICAL COMPONENT IN LIFE SUPPORT OR OTHER SIMILAR SYSTEMS IS NOT AUTHORIZED.

XSEMI DOES NOT ASSUME ANY LIABILITY ARISING OUT OF THE APPLICATION OR USE OF ANY PRODUCT OR CIRCUIT DESCRIBED HEREIN; NEITHER DOES IT CONVEY ANY LICENSE UNDER ITS PATENT RIGHTS, NOR THE RIGHTS OF OTHERS.

XSEMI RESERVES THE RIGHT TO MAKE CHANGES WITHOUT FURTHER NOTICE TO ANY PRODUCTS HEREIN TO IMPROVE RELIABILITY, FUNCTION OR DESIGN.

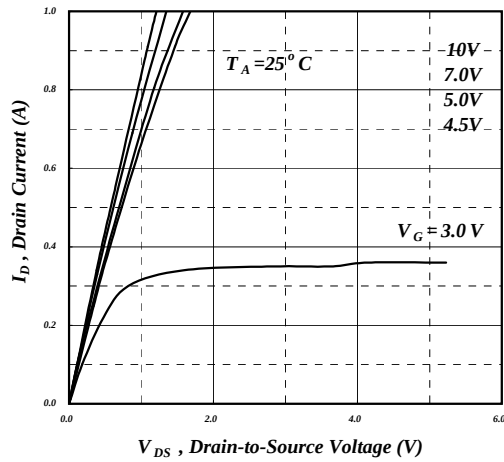


Fig 1. Typical Output Characteristics

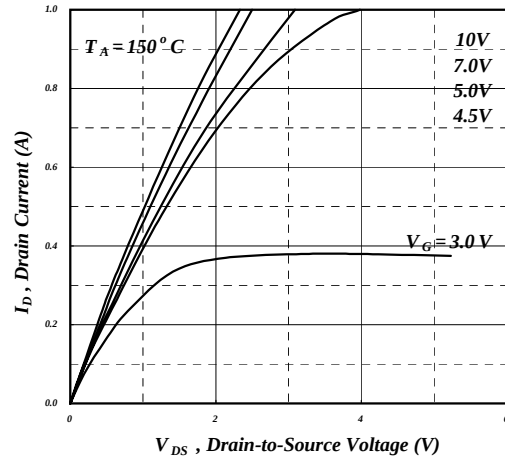


Fig 2. Typical Output Characteristics

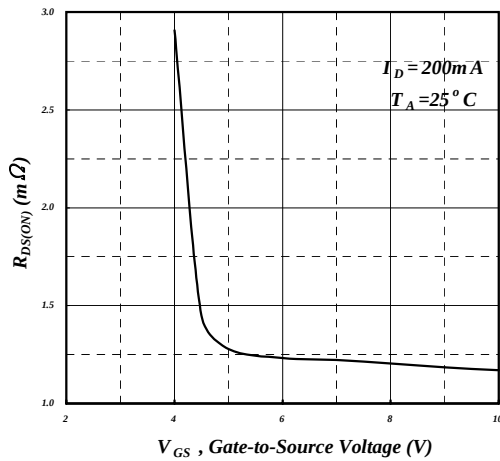
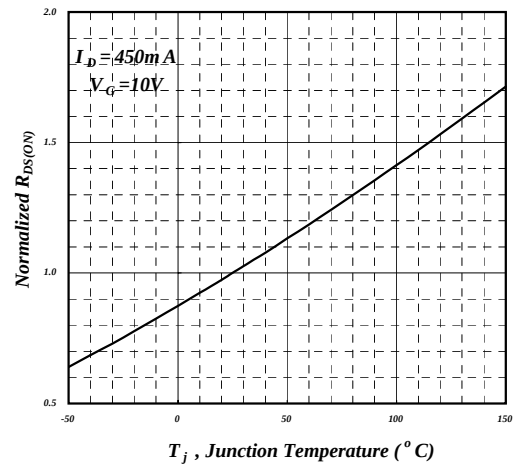
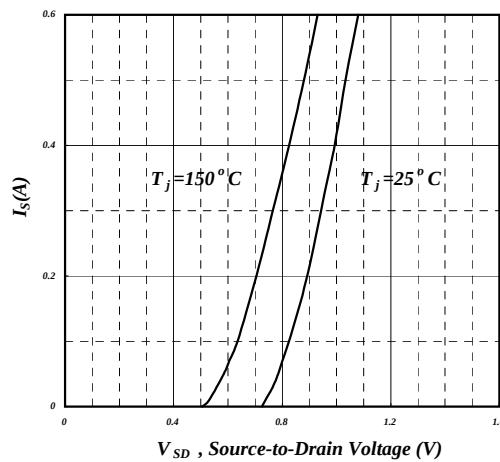


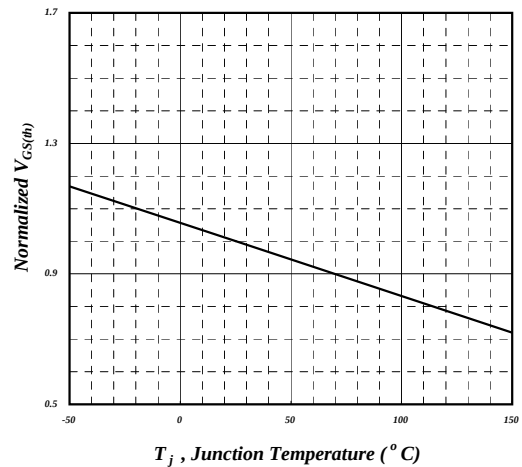
Fig 3. On-Resistance v.s. Gate Voltage



**Fig 4. Normalized On-Resistance
v.s. Junction Temperature**



**Fig 5. Forward Characteristic of
Reverse Diode**



**Fig 6. Gate Threshold Voltage v.s.
Junction Temperature**

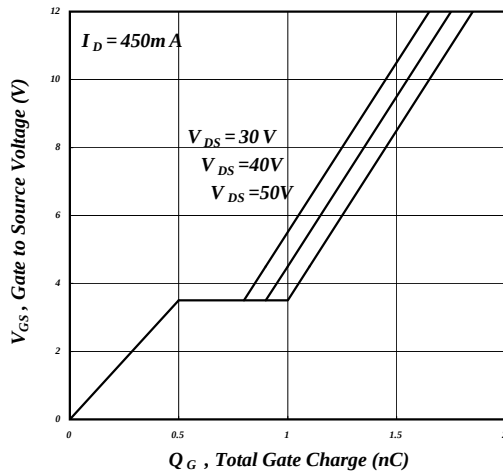


Fig 7. Gate Charge Characteristics

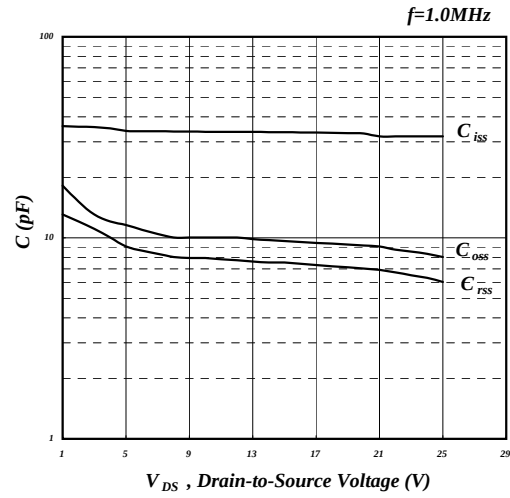


Fig 8. Typical Capacitance Characteristics

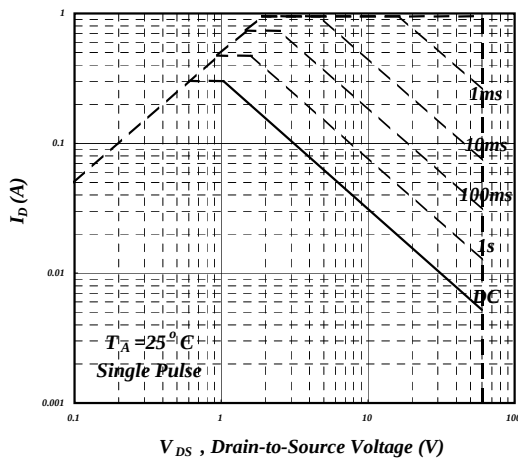


Fig 9. Maximum Safe Operating Area

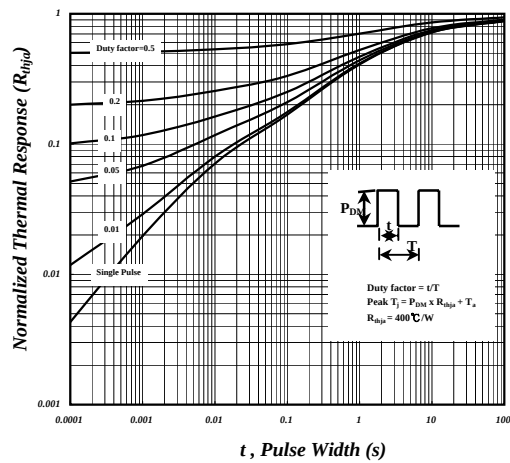


Fig 10. Effective Transient Thermal Impedance

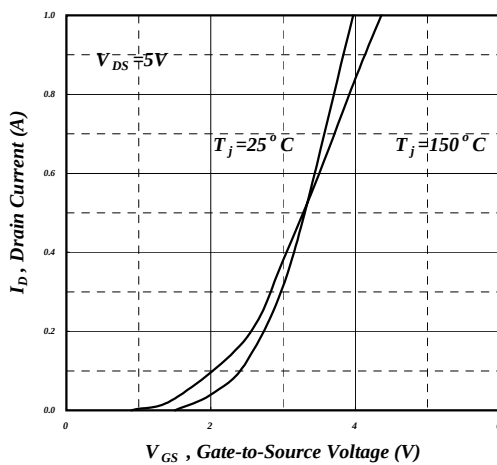


Fig 11. Transfer Characteristics

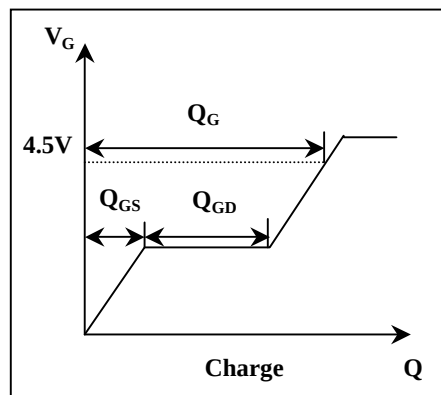
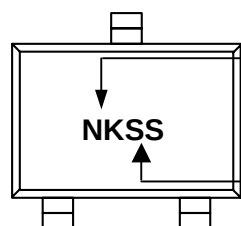


Fig 12. Gate Charge Waveform

MARKING INFORMATION

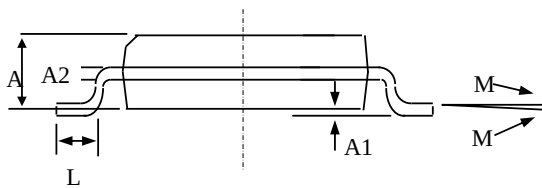
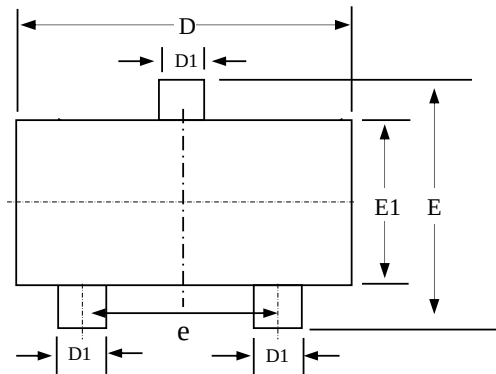
Part Number : NK

Date Code : SS

SS:2004,2008,2012,2016,2020,2024...

SS:2003,2007,2011,2015,2019,2023...SS:2002,2006,2010,2014,2018,2022...SS:2001,2005,2009,2013,2017,2021...

Package Outline : SOT-23S



SYMBOLS	Millimeters		
	MIN	NOM	MAX
A	0.80	1.00	1.20
A1	0.00	—	0.10
A2	0.05	—	0.20
D1	0.30	0.40	0.50
e	1.80	1.90	2.00
D	2.80	2.90	3.10
E	2.10	2.40	2.70
E1	1.20	1.30	1.40
M	0°	5°	10°
L	0.20	—	0.60

1.All Dimension Are In Millimeters.

2.Dimension Does Not Include Mold Protrusions.

SOT-23S FOOTPRINT :

